DATA SHEET

For a complete data sheet, please also download:

- The IC04 LOCMOS HE4000B Logic Family Specifications HEF, HEC
- The IC04 LOCMOS HE4000B Logic Package Outlines/Information HEF, HEC

HEF40097B
buffers
3-state hex non-inverting buffer

Product specification
File under Integrated Circuits, IC04

January 1995

Philips Semiconductors

PHILIPS

3-state hex non-inverting buffer

HEF40097B buffers

DESCRIPTION

The HEF40097B is a hex non-inverting buffer with 3-state outputs. The 3-state outputs are controlled by two enable inputs ($\overline{EO}_4$ and $\overline{EO}_2$). A HIGH on $\overline{EO}_4$ causes four of the six buffer elements to assume a high impedance or OFF-state, regardless of the other input conditions and a HIGH on $\overline{EO}_2$ causes the outputs of the remaining two buffer elements to assume a high impedance or OFF-state, regardless of the other input conditions.

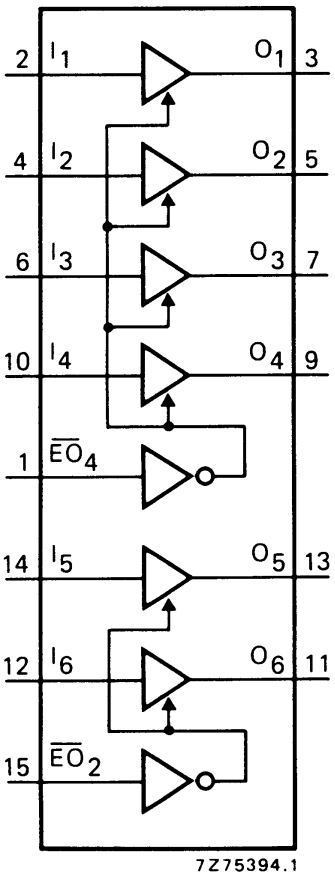

Fig.1 Functional diagram.

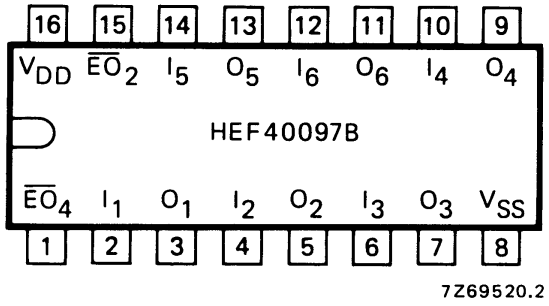

Fig.2 Pinning diagram.

HEF40097BP(N):	16-lead DIL; plastic (SOT38-1)
HEF40097BD(F):	16-lead DIL; ceramic (cerdip) (SOT74)
HEF40097BT(D):	16-lead SO; plastic (SOT109-1)

( ): Package Designator North America

PINNING

I_1 to I_6	buffer inputs
$\overline{EO}_4$, $\overline{EO}_2$	enable inputs (active LOW)
O_1 to O_6	buffer outputs (active HIGH)

FAMILY DATA, I_{DD} LIMITS category BUFFERS

See Family Specifications

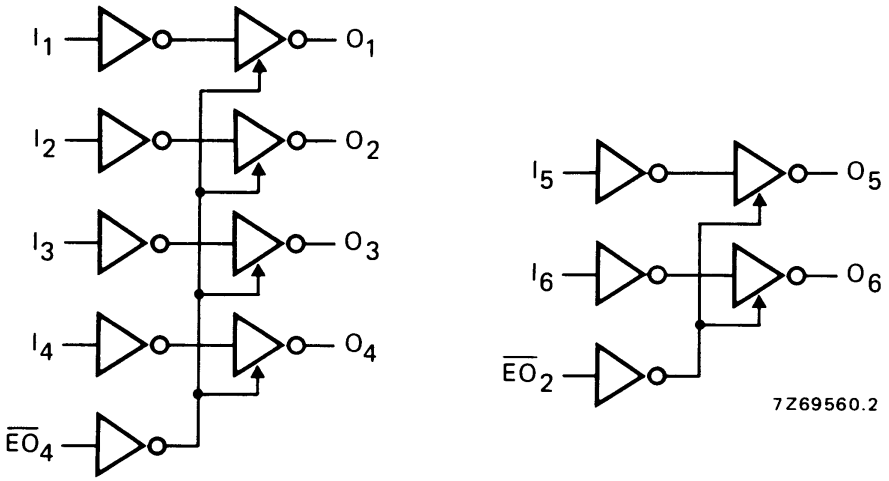

Fig.3 Logic diagram.

DC CHARACTERISTICS

V_{SS} = 0 V

HEF	V_{DD} V	V_{OH} V	V_{OL} V	SYMBOL	T_{amb} (°C)						
					−40		+25		+85		
					MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Output current	5	4,6			1,2		1,0		0,8		mA
HIGH	10	9,5		$-I_{OH}$	3,8		3,2		2,5		mA
	15	13,5			12,0		10,0		8,0		mA
HIGH	5	2,5		$-I_{OH}$	3,8		3,2		2,5		mA
Output current	4,75		0,4		3,5		2,9		2,3		mA
LOW	10		0,5	I_{OL}	12,0		10,0		8,0		mA
	15		1,5		24,0		20,0		16,0		mA

HEC	V_{DD} V	V_{OH} V	V_{OL} V	SYMBOL	T_{amb} (°C)						
					−55		+25		+125		
					MIN.	MAX.	MIN.	MAX.	MIN.	MAX.	
Output current	5	4,6			1,25		1,0		0,6		mA
HIGH	10	9,5		$-I_{OH}$	4,0		3,2		2,1		mA
	15	13,5			12,5		10,0		6,7		mA
HIGH	5	2,5		$-I_{OH}$	4,0		3,2		2,1		mA
Output current	4,75		0,4		3,6		2,9		1,9		mA
LOW	10		0,5	I_{OL}	12,5		10,0		6,7		mA
	15		1,5		25,0		20,0		13,0		mA

AC CHARACTERISTICS

V_{SS} = 0 V; T_{amb} = 25 °C; C_L = 50 pF; input transition times ≤ 20 ns

	V_{DD} V	SYMBOL	TYP.	MAX.		TYPICAL EXTRAPOLATION FORMULA
Propagation delays						
$I_n \rightarrow O_n$	5		70	140	ns	60 ns + (0,20 ns/pF) C_L
HIGH to LOW	10	t_{PHL}	30	60	ns	26 ns + (0,08 ns/pF) C_L
	15		25	50	ns	22 ns + (0,06 ns/pF) C_L
	5		60	120	ns	45 ns + (0,30 ns/pF) C_L
LOW to HIGH	10	t_{PLH}	25	50	ns	19 ns + (0,13 ns/pF) C_L
	15		20	40	ns	16 ns + (0,09 ns/pF) C_L
Output transition times	5		30	60	ns	15 ns + (0,30 ns/pF) C_L
HIGH to LOW	10	t_{THL}	15	30	ns	10 ns + (0,11 ns/pF) C_L
	15		10	20	ns	7 ns + (0,07 ns/pF) C_L
	5		35	70	ns	10 ns + (0,50 ns/pF) C_L
LOW to HIGH	10	t_{TLH}	20	40	ns	8 ns + (0,24 ns/pF) C_L
	15		15	30	ns	6 ns + (0,18 ns/pF) C_L
3-state propagation delays						
Output disable times						
$\overline{EO}_2$, $\overline{EO}_4 \rightarrow O_n$	5		45	95	ns	
HIGH	10	t_{PHZ}	35	70	ns	
	15		30	60	ns	
	5		60	120	ns	
LOW	10	t_{PLZ}	35	70	ns	
	15		25	55	ns	
Output enable times						
$\overline{EO}_2$, $\overline{EO}_4 \rightarrow O_n$	5		75	150	ns	
HIGH	10	t_{PZH}	35	70	ns	
	15		30	60	ns	
	5		95	190	ns	
LOW	10	t_{PZL}	40	80	ns	
	15		30	65	ns	

	V_{DD} V	TYPICAL FORMULA FOR P (μW)	
Dynamic power dissipation per package (P)	5	5 400 $f_i + \sum (f_o C_L) \times V_{DD}^2$	where f_i = input freq. (MHz) f_o = output freq. (MHz) C_L = load cap. (pF) $\sum (f_o C_L)$ = sum of outputs V_{DD} = supply voltage (V)
	10	25 200 $f_i + \sum (f_o C_L) \times V_{DD}^2$	
	15	96 500 $f_i + \sum (f_o C_L) \times V_{DD}^2$	